NSN 5961-01-262-6048

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View Online at https://aerobasegroup.com/nsn/5961-01-262-6048 **Inclosure Material:** Metal **Overall Length:** 1.330 inches **End Application:** 1440-01-217-2334 **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 drain to source voltage **Current Rating Per Characteristic:** 30.00 amperes drain current **Power Rating Per Characteristic:** 150.0 watts total power dissipation **Special Features:** Hardness critical process **Nuclear Hardness Critical Feature:** Hardened **Test Data Document:** 19200-12325157 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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